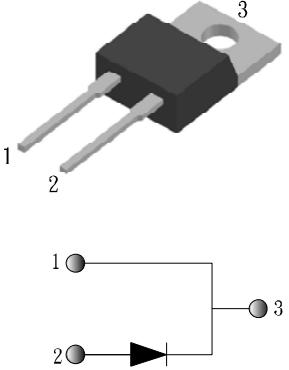
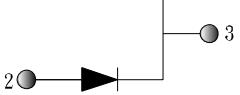


<u>TO-220AC</u>  	<p>Features</p> <ul style="list-style-type: none"> • ROHS Compliant • Metal silicon junction, majority carrier conduction • Guard ring for stress protection • Low forward voltage drop • High forward surge capability • High current capability • Solder dip 260 °C / 10S <p>PB</p>																																												
	<p>Applications</p> <p>Ideal for solar PV application such as by-pass diode</p>																																												
<p>Primary characteristics</p> <table border="1"> <tbody> <tr> <td>$I_{F(AV)}$</td><td>15A</td></tr> <tr> <td>V_{RRM}</td><td>45V</td></tr> <tr> <td>I_{FSM}</td><td>300A</td></tr> <tr> <td>V_F</td><td>0.43V</td></tr> <tr> <td>T_J max. DC forward mode</td><td>125 °C 200 °C</td></tr> </tbody> </table>	$I_{F(AV)}$	15A	V_{RRM}	45V	I_{FSM}	300A	V_F	0.43V	T_J max. DC forward mode	125 °C 200 °C	<p>Mechanical data</p> <ul style="list-style-type: none"> • Case: TO-220AC, molded plastic • Epoxy meets UL 94 V-0 flammability rating • Terminals: Tin plated leads. • Polarity: As marked • Weight: 2.01 grams 																																		
$I_{F(AV)}$	15A																																												
V_{RRM}	45V																																												
I_{FSM}	300A																																												
V_F	0.43V																																												
T_J max. DC forward mode	125 °C 200 °C																																												
	<p>Maximum rating (Ta=25 °C unless otherwise noted)</p> <table border="1"> <thead> <tr> <th>Parameter</th><th>Symbol</th><th>SPST15L45</th><th>Unit</th></tr> </thead> <tbody> <tr> <td>Max. repetitive peak reverse voltage</td><td>V_{RRM}</td><td>45</td><td>V</td></tr> <tr> <td>Max. RMS reverse voltage</td><td>V_{RMS}</td><td>31</td><td></td></tr> <tr> <td>Max. DC blocking voltage</td><td>V_{DC}</td><td>45</td><td>V</td></tr> <tr> <td>Max. average forward current (see Fig.1)</td><td>$I_{F(AV)}$</td><td>15</td><td>A</td></tr> <tr> <td>Non-repetitive peak forward surge current 8.3ms single half-sine-wave</td><td>I_{FSM}</td><td>300</td><td>A</td></tr> <tr> <td>Rating for fusing, $1ms \leq t \leq 8.3ms$</td><td>I^2t</td><td>373</td><td>A^2S</td></tr> <tr> <td>Operating junction temperature</td><td>T_J</td><td>-50 ~ +125</td><td>°C</td></tr> <tr> <td>Max. junction temperature in DC forward mode</td><td>T_J</td><td>200</td><td>°C</td></tr> <tr> <td>Storage temperature</td><td>T_{STG}</td><td>-50 ~ +125</td><td>°C</td></tr> <tr> <td>Thermal resistance junction to case⁽¹⁾</td><td>R_{EJ-C}</td><td>1.5</td><td>°C/W</td></tr> </tbody> </table>	Parameter	Symbol	SPST15L45	Unit	Max. repetitive peak reverse voltage	V_{RRM}	45	V	Max. RMS reverse voltage	V_{RMS}	31		Max. DC blocking voltage	V_{DC}	45	V	Max. average forward current (see Fig.1)	$I_{F(AV)}$	15	A	Non-repetitive peak forward surge current 8.3ms single half-sine-wave	I_{FSM}	300	A	Rating for fusing, $1ms \leq t \leq 8.3ms$	I^2t	373	A^2S	Operating junction temperature	T_J	-50 ~ +125	°C	Max. junction temperature in DC forward mode	T_J	200	°C	Storage temperature	T_{STG}	-50 ~ +125	°C	Thermal resistance junction to case ⁽¹⁾	R_{EJ-C}	1.5	°C/W
Parameter	Symbol	SPST15L45	Unit																																										
Max. repetitive peak reverse voltage	V_{RRM}	45	V																																										
Max. RMS reverse voltage	V_{RMS}	31																																											
Max. DC blocking voltage	V_{DC}	45	V																																										
Max. average forward current (see Fig.1)	$I_{F(AV)}$	15	A																																										
Non-repetitive peak forward surge current 8.3ms single half-sine-wave	I_{FSM}	300	A																																										
Rating for fusing, $1ms \leq t \leq 8.3ms$	I^2t	373	A^2S																																										
Operating junction temperature	T_J	-50 ~ +125	°C																																										
Max. junction temperature in DC forward mode	T_J	200	°C																																										
Storage temperature	T_{STG}	-50 ~ +125	°C																																										
Thermal resistance junction to case ⁽¹⁾	R_{EJ-C}	1.5	°C/W																																										

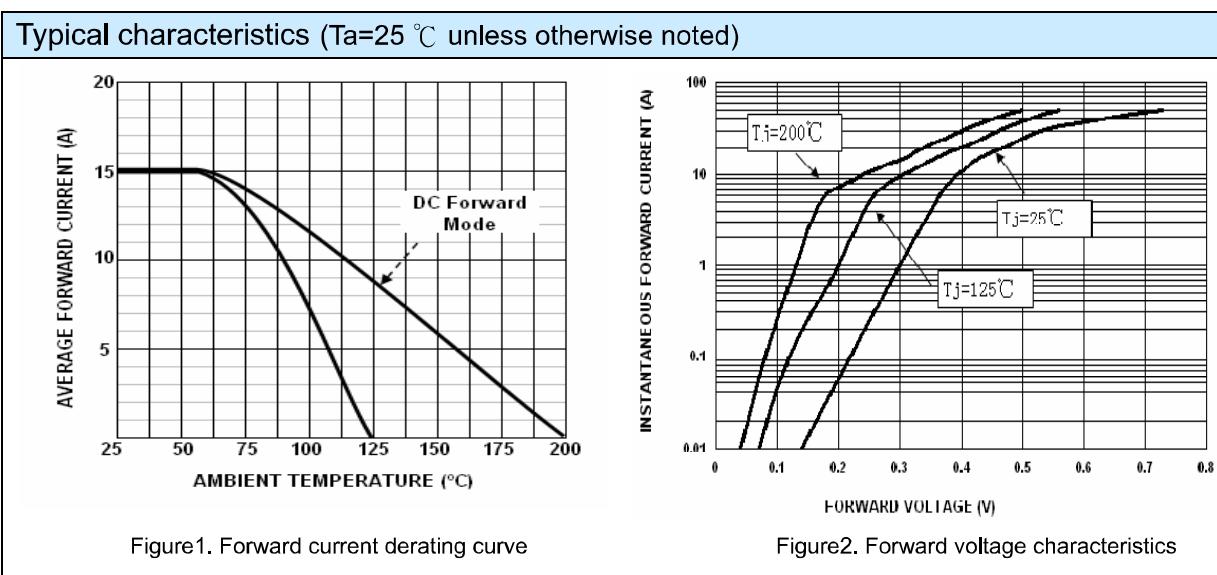
Note: (1) Leads are kept at ambient temperature at a distance of 10 mm from case

(2) Pulse test with PW=300us, 1%duty cycle.

Maximum rating (Ta=25 °C unless otherwise noted)						
Parameter	Test condition		Symbol	Min.	Typ.	Max.
Forward voltage drop ⁽²⁾	T _J =25°C	I _F =5A	V _F	-	0.36	0.40
	T _J =125°C			-	0.25	-
	T _J =200°C			-	0.17	-
	T _J =25°C	I _F =8A	V _F	-	0.39	0.42
	T _J =125°C			-	0.29	-
	T _J =200°C			-	0.22	-
	T _J =25°C	I _F =12A	V _F	-	0.41	-
	T _J =125°C			-	0.33	-
	T _J =200°C			-	0.27	-
	T _J =25°C	I _F =15A	V _F	-	0.43	0.50
	T _J =125°C			-	0.36	-
	T _J =200°C			-	0.31	-
Reverse leakage current	T _J =25°C	V _R =V _{RRM}	I _R	-	0.25	1
	T _J =100°C			-	-	50.0

Note: (1) Leads are kept at ambient temperature at a distance of 10 mm from case

(2) Pulse test with PW=300us, 1%duty cycle.



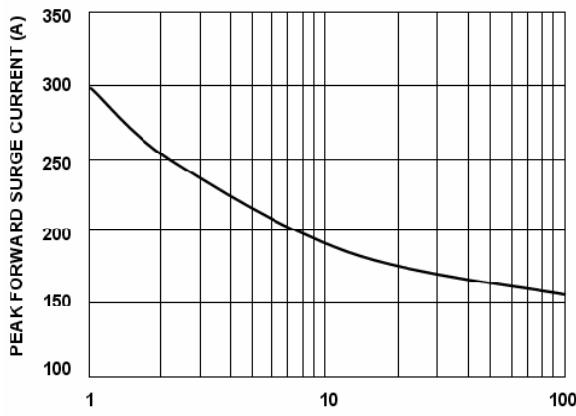
Typical characteristics (Ta=25 °C unless otherwise noted)


Figure3. Non-repetitive surge current

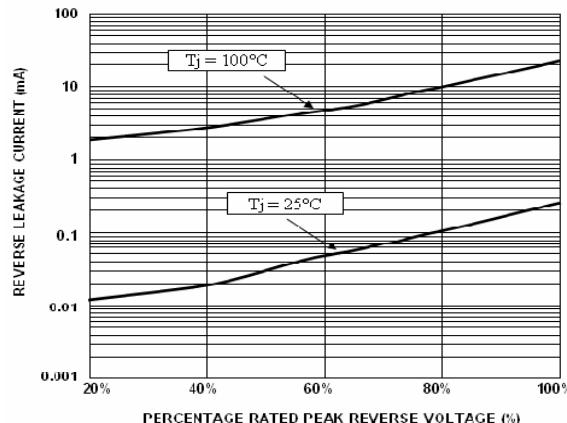
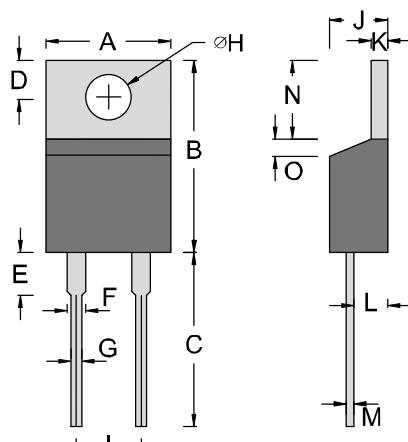


Figure4. Reverse current characteristics

Package outline dimensions


Dim.	Inches		Millimeters	
	Min.	Max.	Min.	Max.
A	0.038	0.405	9.65	10.29
B	0.595	0.620	15.11	15.75
C	0.500	0.562	12.70	14.27
D	0.100	0.120	2.54	3.04
E	0.110	0.130	2.79	3.30
F	0.045	0.060	1.14	1.52
G	0.025	0.035	0.64	0.89
H	0.142	0.147	3.61	3.73
I	0.190	0.210	4.83	5.33
J	0.160	0.190	4.06	4.82
K	0.045	0.055	1.14	1.39
L	0.080	0.110	2.04	2.79
M	0.018	0.025	0.46	0.64
N	0.235	0.255	5.97	6.48
O	0.000	0.050	0.00	1.27

SiPower Inc. - Legal Notice

Disclaimer – All data and specifications are subject to changes without notice

SiPower Inc, it's affiliates, agents, distributors and employees neither accept nor assume any responsibility for errors or inaccuracies. All data and specifications are intended for information and provide a product description only. Electrical and mechanical parameters listed in SiPower data sheets and specifications will vary dependent upon application and environmental conditions . SiPower is not liable for any damages occurred or resulting from any circuit, product or end-use application for which it's products are used. SiPower products are not intended or designed for use in life saving or sustaining apparatus and purchase of any SiPower products automatically indemnifies SiPower against any claims or damages resulting from application malfunction.